



SM-G991U/0/D/V/S
00 T42

USQR6.0

0.63
T60

SM-G991B

R7

#1 T2

MAIN

1 MAIN 55
2 MAIN 56

60 MAIN 2
59 MAIN 1

bB25

20
DL

Samsung
Model
Seco
Nomin
Rated
Typical

SM-G991 CTC PBA
DS. HF. R RD.3 K4.6. SI

CELL MADE IN CHINA, ASSEMBLED IN CHINA
中國製造/中國製造 製造
BY, 제조자 / Manufacturer: Ningde
電池組 / 二次鋰電池組, A/S
電壓 / 정격: 3.88 V =, 執行標
電容量: 3880 mAh, 15.06 Wh,
Wh, 充電限制電壓: 4.47 V

ICT 廢電池請回收

R33475

US
MH29195

do not crush, puncture,
use. Authorized Service Provider Only.
印、穿刺、燃燒或重複使用。

2 UB 56
1 UB 55

SM-G991U CTC FPCB R0.5
S.KA4 G (KH) K

60 SUB 2 7359
59 SUB 1

SM-G991U LEGACY FRC REVL.H LF-AG

EI DB IS

n 00
(Part 2)
133-2

R020.10.12

624XTQ RLV3.3

6991U/0_VP_002
D00A

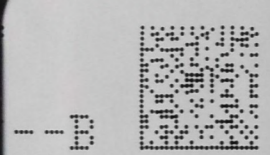
J-PH JUC100



1 MAIN 55
2 MAIN 56

bB25

SM-G991 CTC PBA
DS. HF. R RD.3 K4.6.SI



CELL MADE IN CHINA, ASSEMBLED IN CHINA
中國製造/中國製造 製造商: 寧德新能能源科技有限公司
BY, 제조자 / Manufacturer: Ningde Ampere Technology Limited
電池組/二次鋰電池組, AS 연락처: 1588-3366
電壓 / 정격: 3.88 V =, 執行標準: GB 31241-2014
電容量: 3880 mAh, 15.06 Wh, 1ICP6/61/70
Wh, 充電限制電壓: 4.47 V =



UL US MH29195
YU10427 -20025

IS 16046(Part 2)
/IEC 62133-2
R-41137359
www.bis.gov.in

2 UB 56
1 UB 55

